

# PHOTO DIODE NR6800 Series

# $\phi$ 80 $\mu$ m InGaAs AVALANCHE PHOTO DIODE FOR OTDR APPLICATIONS

#### DESCRIPTION

The NR6800 Series is an InGaAs avalanche photo diode, and can be used in OTDR systems.

#### FEATURES

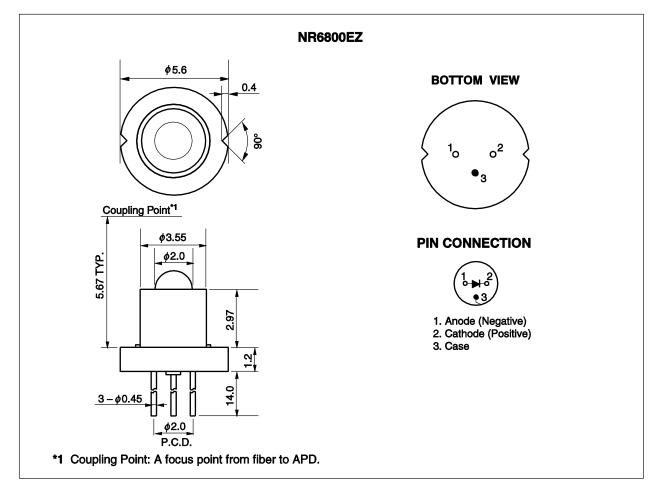
- Small dark current ID = 5 nA
- Small terminal capacitance  $$C_t=0.50\ pF\ @\ 0.9\ V_{(BR)R}$$
- High sensitivity
- High speed response
- fc = 1.0 GHz MIN. @ λ = 1 310 nm, M = 10 φ 80 μm

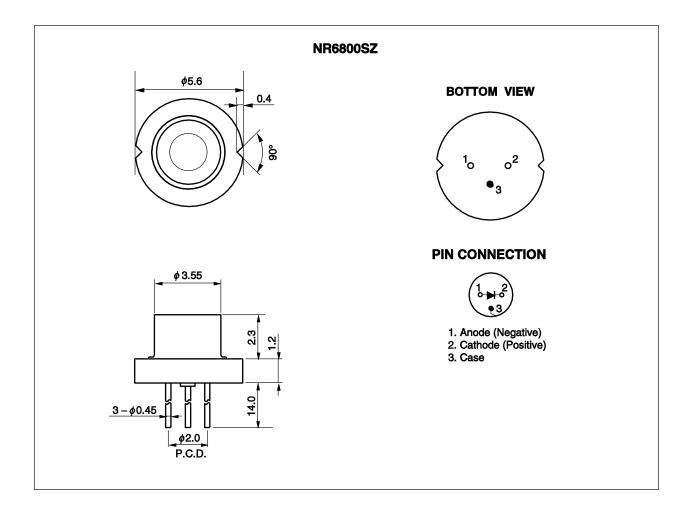
S = 0.94 A/W @  $\lambda$  = 1 310 nm, M = 1

Detecting area size

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

## PACKAGE DIMENSION (UNIT: mm)





#### ORDERING INFORMATION

Part Number	Package
NR6800EZ-AZ	3-pin CAN with ball lens cap
NR6800SZ-AZ	3-pin CAN with flat glass cap

Remarks 1. The color of ball lens cap might be observed differently.2. The hermetic test will be performed as AQL 1.0%.

#### ABSOLUTE MAXIMUM RATINGS

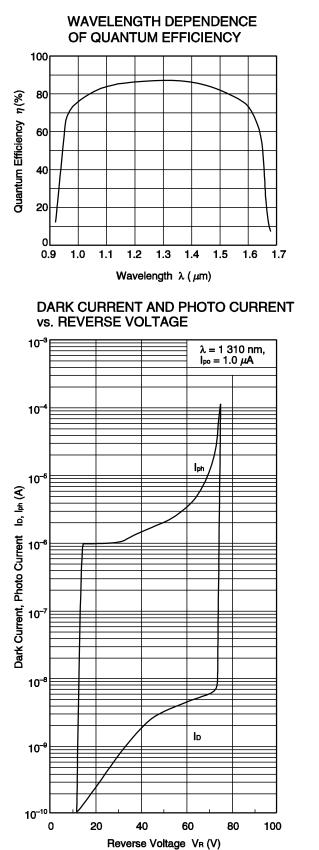
Parameter	Symbol	Ratings	Unit
Forward Current	lF	10	mA
Reverse Current	IR	0.5	mA
Operating Case Temperature	Tc	-40 to +85	°C
Storage Temperature	Tstg	-40 to +85	°C
Lead Soldering Temperature	Tsld	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

# ELECTRO-OPTICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)

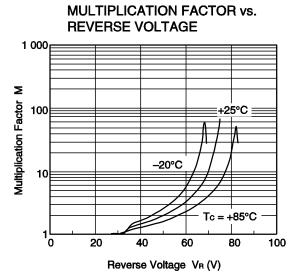
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Reverse Breakdown Voltage	VBR	Ι <sub>D</sub> = 100 μA	50	70	100	V
Temperature Coefficient of Reverse Breakdown Voltage	δ*1			0.2		%/°C
Dark Current	lo	$V_R = V_{BR} \times 0.9$		5	30	nA
Terminal Capacitance	Ct	$V_R = V_{BR} \times 0.9$ , f = 1 MHz		0.50	0.75	pF
Cut-off Frequency	fc	$\lambda = 1 \ 310 \ \text{nm}, \ \text{M} = 10$	1.0			GHz
Sensitivity	S	$\lambda = 1 \ 310 \ \text{nm}, \ \text{M} = 1$	0.80	0.94		A/W
Multiplication Factor	М	$\lambda$ = 1 310 nm, I <sub>po</sub> = 1.0 $\mu$ A,	30	50		
		$V_{R} = V (@ I_{D} = 1 \ \mu A)$				

\*1  $\delta = \frac{V_{BR} (25^{\circ}C + \varDelta T^{\circ}C) - V_{BR} (25^{\circ}C)}{\varDelta T^{\circ}C \cdot V_{BR} (25^{\circ}C)}$ 

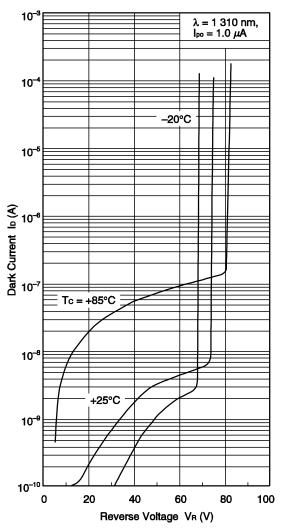
#### TYPICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)







#### DARK CURRENT vs. REVERSE VOLTAGE



### REFERENCE

Document Name	Document No.	
Opto-Electronics Devices Pamphlet	PX10160E	

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.	
	<ul> <li>Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.</li> </ul>	
	<ol> <li>Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> </ol>	
	<ol><li>Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li></ol>	
	• Do not burn, destroy, cut, crush, or chemically dissolve the product.	
	• Do not lick the product or in any way allow it to enter the mouth.	
Caution Optical Fiber	<ul><li>A glass-fiber is attached on the product. Handle with care.</li><li>When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.</li></ul>	

#### SAFETY INFORMATION ON THIS PRODUCT